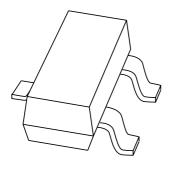
## **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# **BAT720**Schottky barrier diode

Product specification Supersedes data of 1999 May 26 2003 Mar 25





## Schottky barrier diode

#### **BAT720**

#### **FEATURES**

- · Ultra high switching speed
- · Low forward voltage
- · Guard ring protected
- Small plastic SMD package.

#### **APPLICATIONS**

- Ultra high-speed switching
- Voltage clamping
- Protection circuits.

#### **DESCRIPTION**

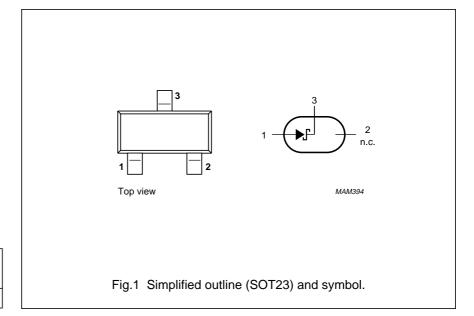
Planar Schottky barrier diode with an integrated guard ring for stress protection in a small SOT23 plastic SMD package.

#### **MARKING**

TYPE NUMBER	MARKING CODE <sup>(1)</sup>	
BAT720	L6*	

## PINNING

PIN	DESCRIPTION	
1	anode	
2	not connected	
3	cathode	



#### Note

\* = p : Made in Hong Kong.
 \* = t : Made in Malaysia.

\* = W : Made in China.

#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>R</sub>	continuous reverse voltage		_	40	V
I <sub>F</sub>	continuous forward current		_	500	mA
I <sub>FSM</sub>	non-repetitive peak forward current	t <sub>p</sub> < 10 ms	_	2	Α
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>j</sub>	junction temperature		_	125	°C

## Schottky barrier diode

**BAT720** 

#### **ELECTRICAL CHARACTERISTICS**

 $T_j$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 500 mA; see Fig.2	_	550	mV
I <sub>R</sub>	reverse current	V <sub>R</sub> = 35 V; see Fig.3	_	100	μΑ
		V <sub>R</sub> = 35 V; T <sub>j</sub> = 100 °C; see Fig.3	_	10	mA
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 0; see Fig.4	60	90	pF

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT	
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	500	K/W	

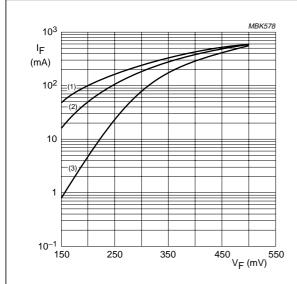
#### Note

1. Refer to SOT23 standard mounting conditions.

## Schottky barrier diode

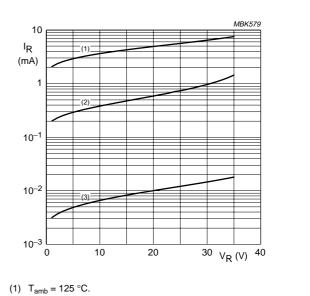
**BAT720** 

#### **GRAPHICAL DATA**



- (1)  $T_{amb} = 125 \,^{\circ}C$ .
- (2)  $T_{amb} = 85 \text{ °C}.$ (3)  $T_{amb} = 25 \text{ °C}.$

Fig.2 Forward current as a function of forward voltage; typical values.



- (2)  $T_{amb} = 85 \,^{\circ}\text{C}$ . (3)  $T_{amb} = 25 \,^{\circ}\text{C}$ .

Fig.3 Reverse current as a function of reverse voltage; typical values.

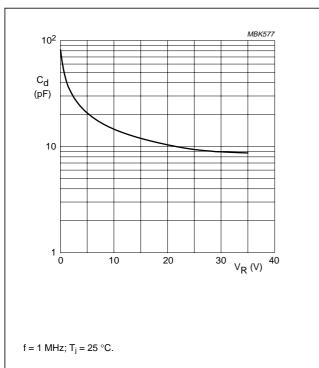


Fig.4 Diode capacitance as a function of reverse voltage; typical values.

2003 Mar 25 4

## Schottky barrier diode

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#### **PACKAGE OUTLINE**

UNIT

max.

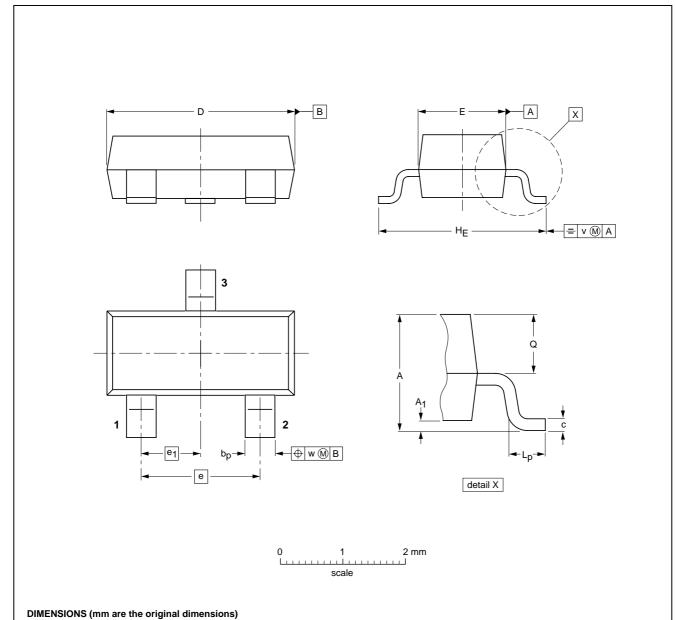
0.48

0.15

1.1 0.9

Plastic surface mounted package; 3 leads

SOT23



OUTLINE		REFERENCES				ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ	PROJECTION		ISSUE DATE	
SOT23		TO-236AB				<del>97-02-28</del> 99-09-13	

 $L_{p}$ 

0.45

 $H_{\mathsf{E}}$ 

Q

0.55

w

0.1

Ε

1.9

#### Schottky barrier diode

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#### **DATA SHEET STATUS**

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

#### **Notes**

- Please consult the most recently issued data sheet before initiating or completing a design.
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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

#### **DEFINITIONS**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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## Schottky barrier diode

**BAT720** 

NOTES

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